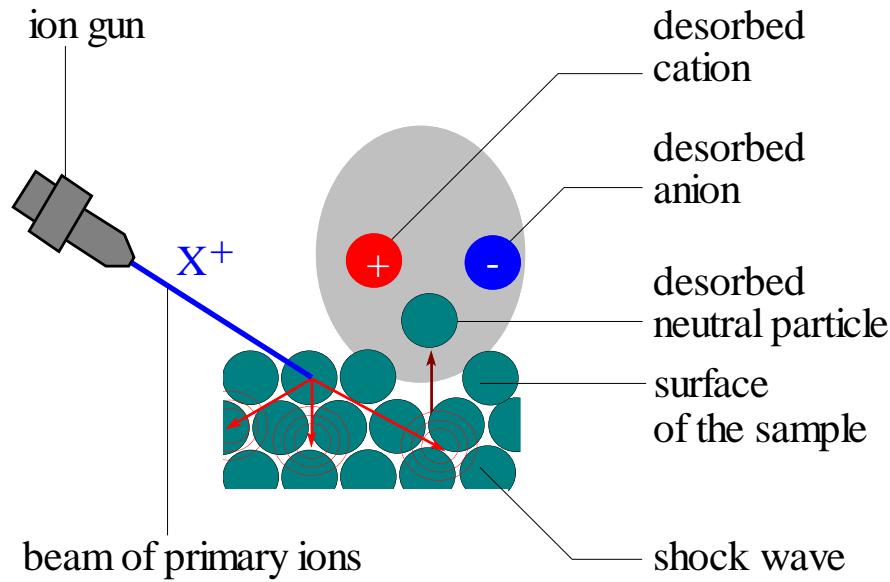


Chemical analysis of surfaces and organic thin films by means of SIMS



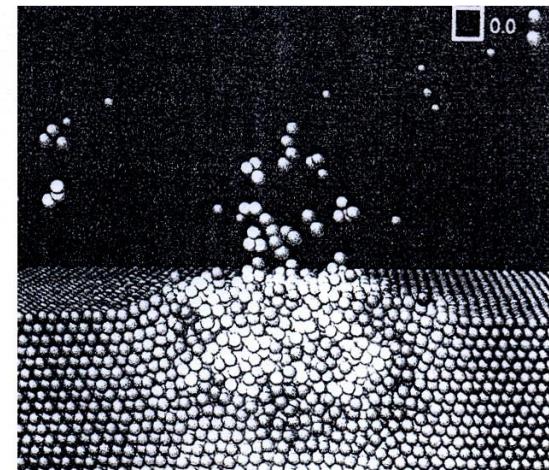
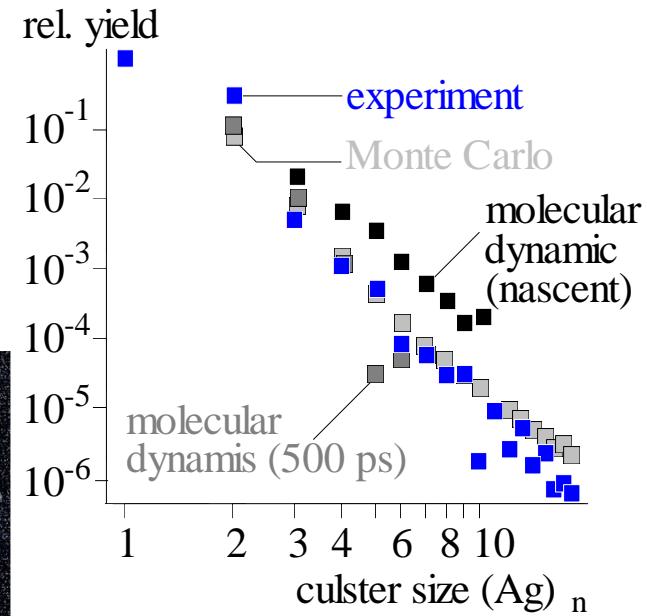
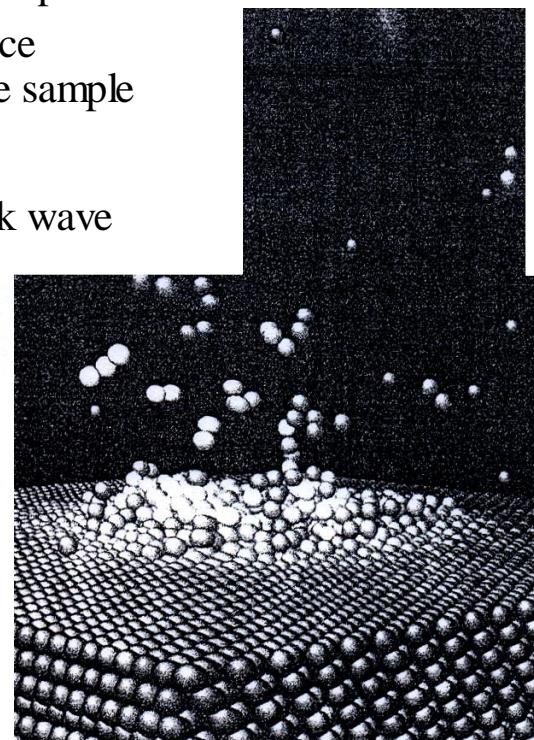
Secondary ion mass spectrometry (SIMS)

– Static SIMS (SSIMS) vs. dynamic SIMS –



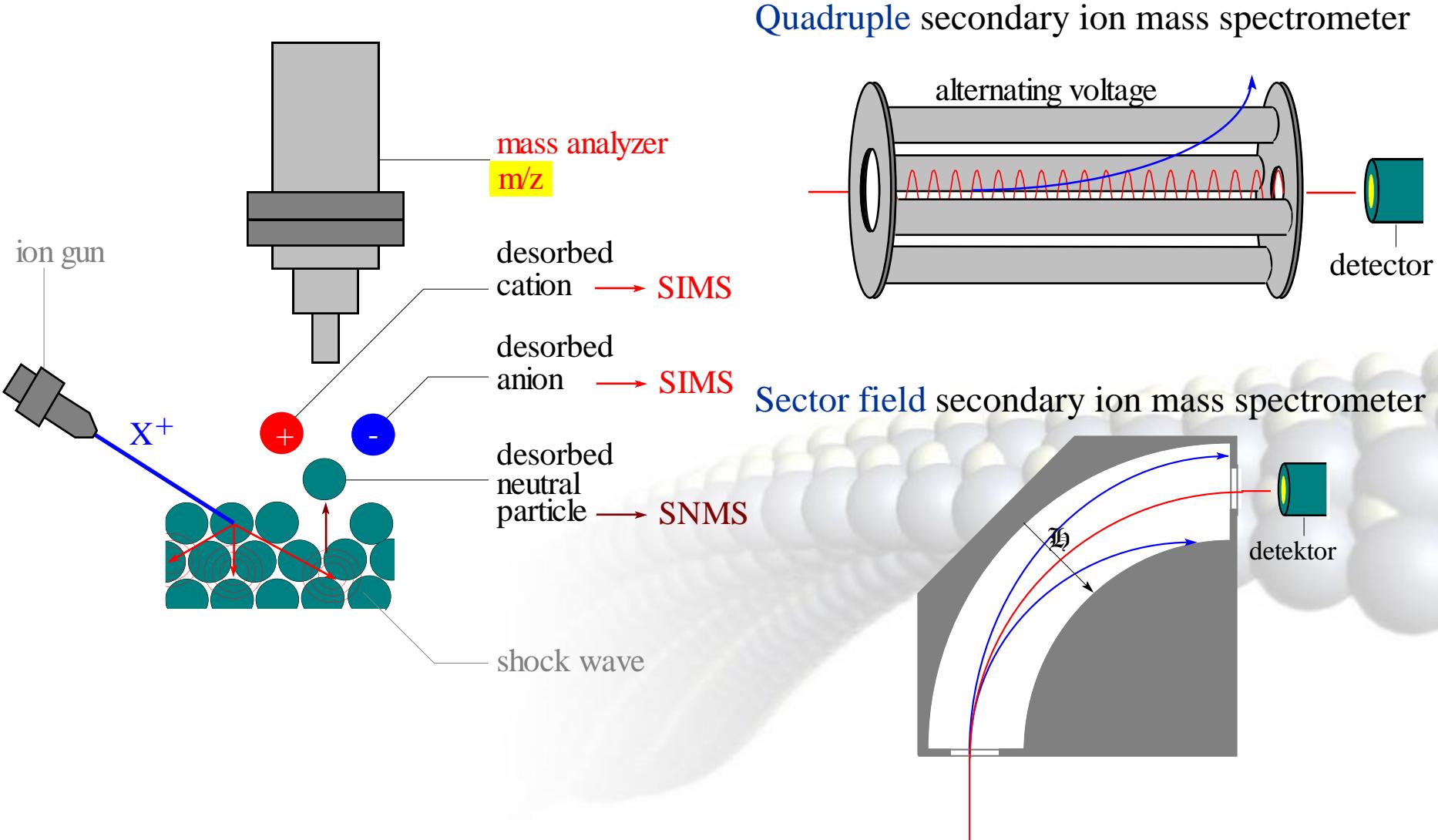
Cu (111) surface 1 ps after the bombardment with a Cu atom having an energy of 5 keV.

(H.M. Urbassek: Molecular-dynamic simulation of sputtering. Nuclear Instruments and methods in Physics Research, VOL B 122 (1997), S. 427-441)

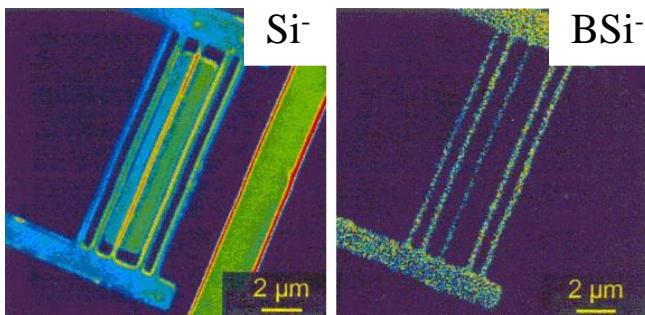
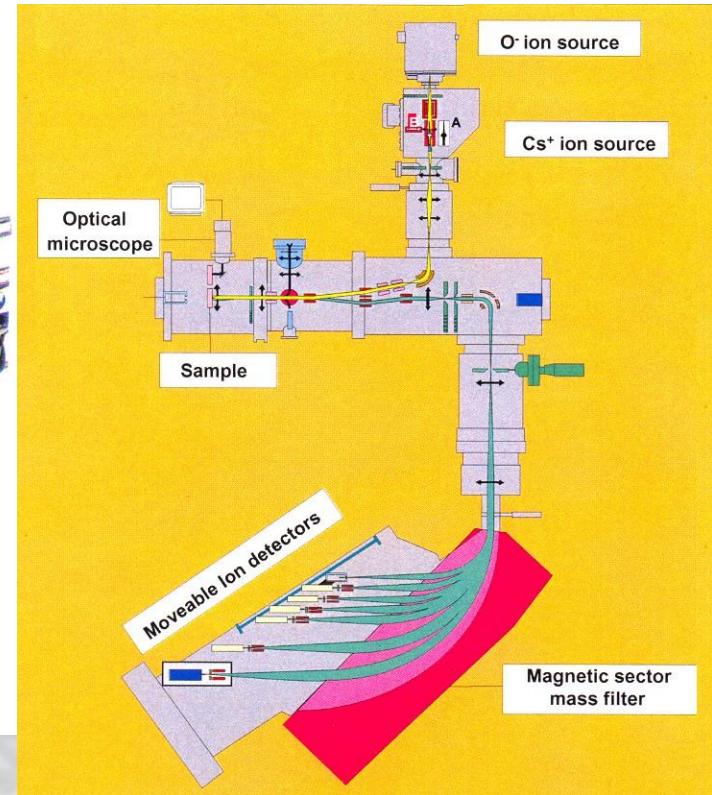
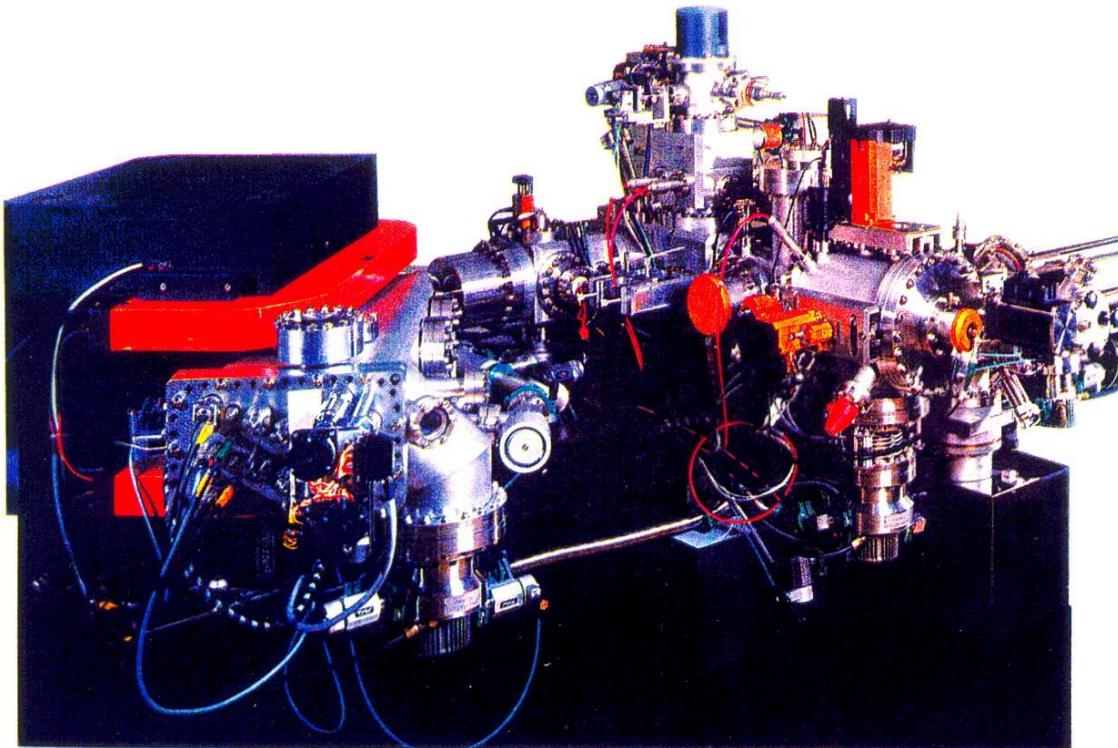


Secondary ion mass spectrometry (SIMS)

– Units to separate (molecule) ions of different masses –



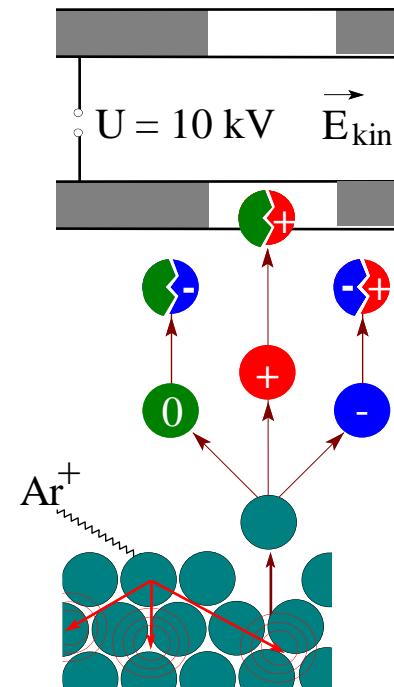
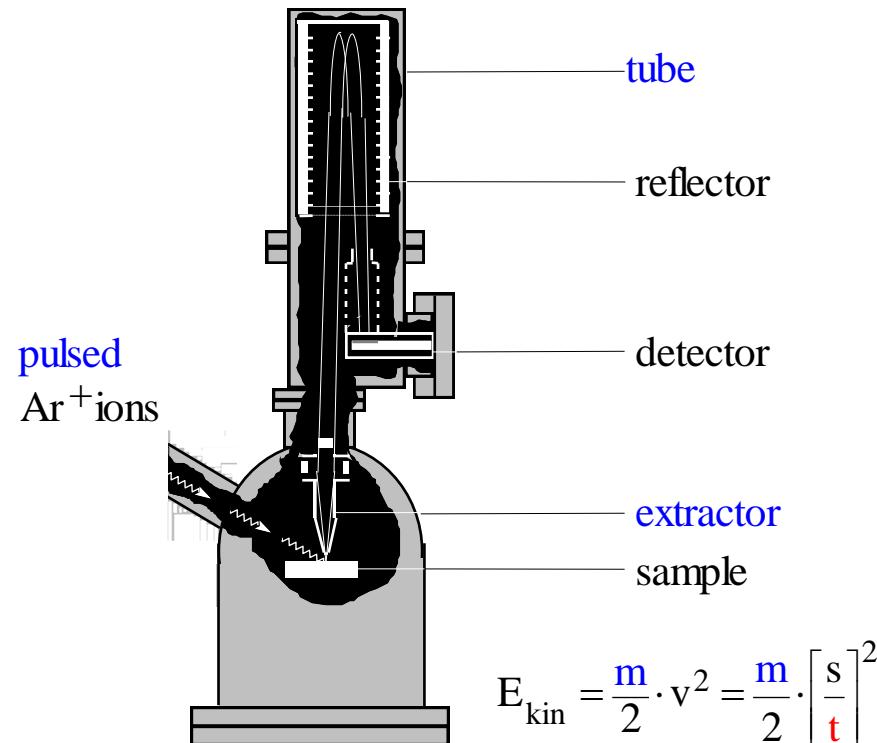
Sector field secondary ion mass spectrometer – NanoSIMS 50 (Cameca, Paris, France) –



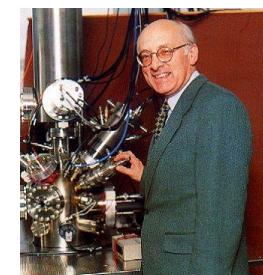
silicon doped with boron,
line width 0,14 μm,
acquisition time: 16 min (ONERA, France)

Static secondary ion mass spectrometry (SSIMS)

– Time-of-Flight Secondary Ion Mass Spectrometry (ToF-SIMS) –



A. Benninghoven



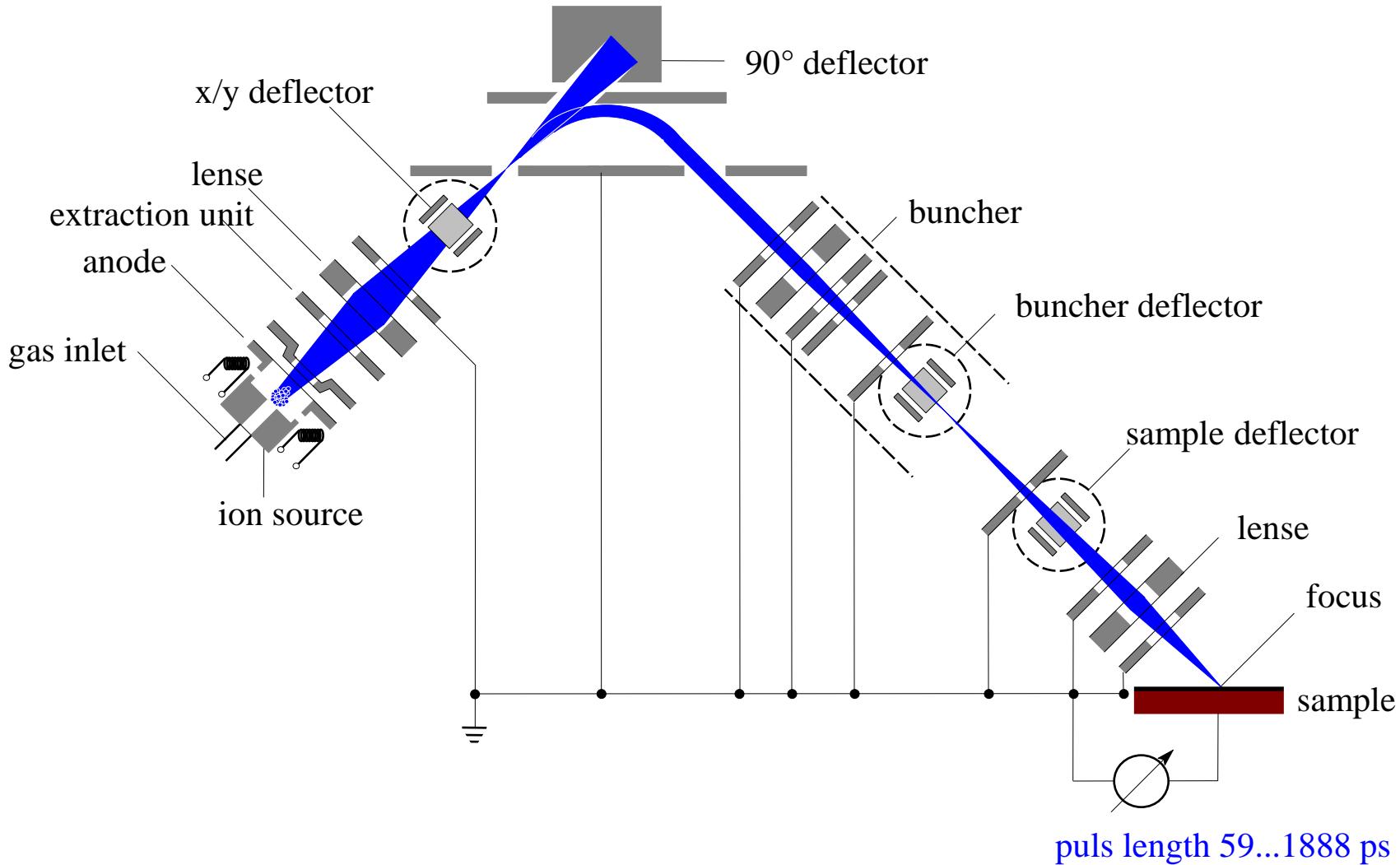
J.C. Vickerman



Charles Evans

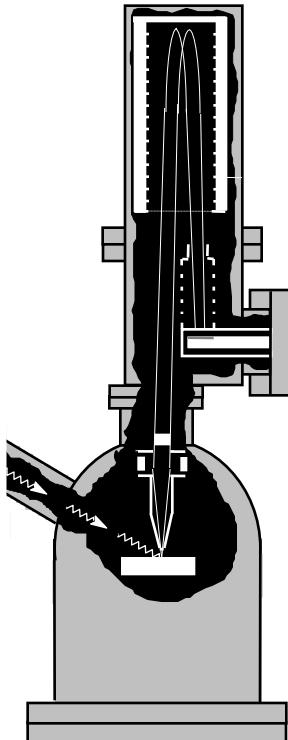
Time-of-Flight Secondary Ion Mass Spectrometry (ToF-SIMS)

– Pulsed primary ion beam –

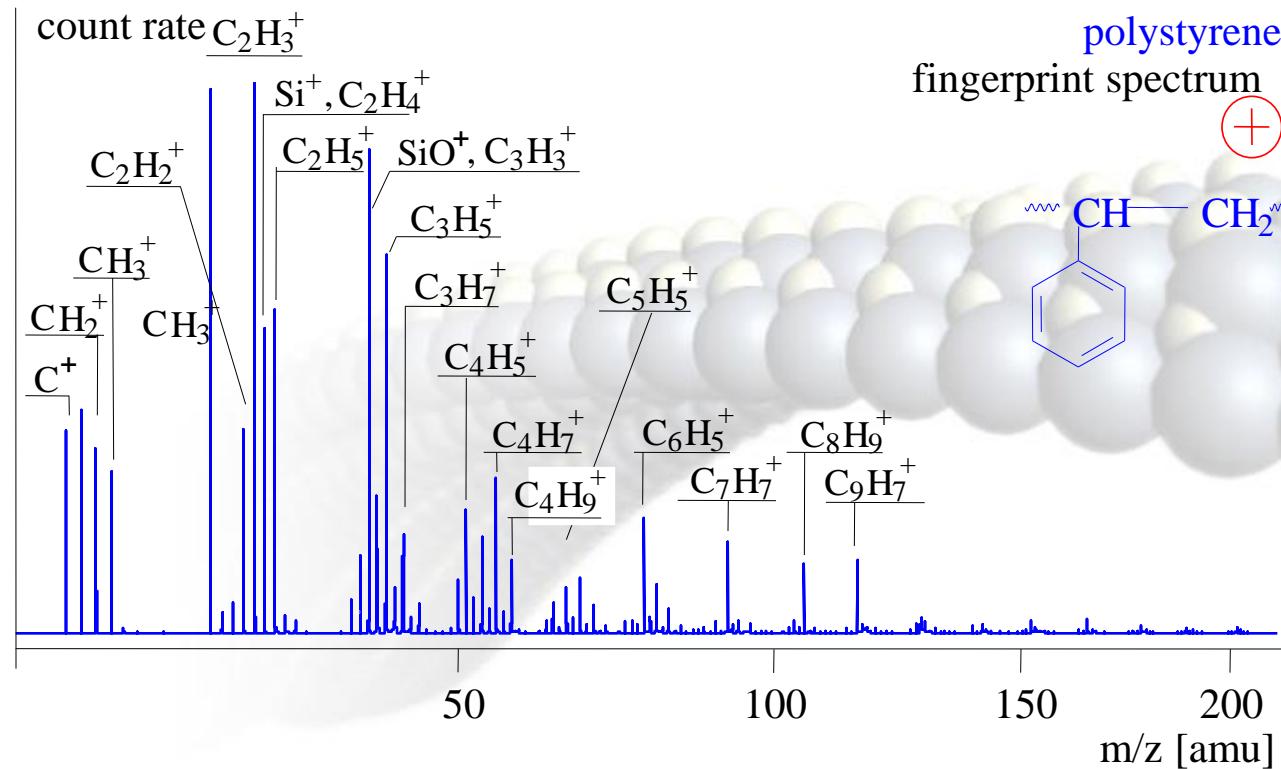


Time-of-Flight Secondary Ion Mass Spectrometry (ToF-SIMS)

– Spectral information –



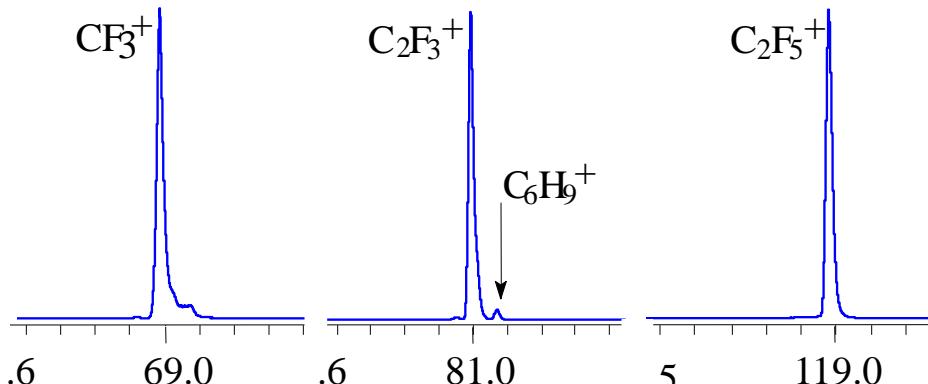
$$E_{\text{kin}} = \frac{m}{2} \cdot v^2 = \frac{m}{2} \cdot \left[\frac{s}{t} \right]^2$$



Time-of-Flight Secondary Ion Mass Spectrometry (ToF-SIMS)

– Excellent mass resolution – PTFE after its treatment in a hydrogen plasma –

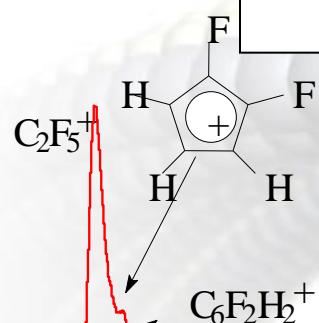
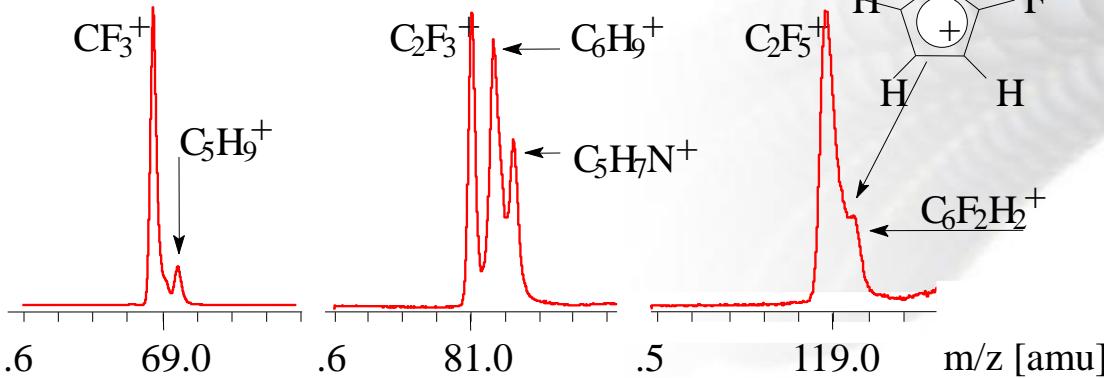
unmodified PTFE



m/z	measured m_m	calculated m_c	$\Delta = m_m - m_c $
CF_3^+	68.9873	68.9952	0.0079
C_5H_9^+	69.0695	69.0717	0.0022
C_2F_3^+	80.9888	80.9952	0.0064
C_6H_9^+	81.0645	81.0717	0.0072
C_2F_5^+	118.9858	118.9920	0.0062
$\text{C}_6\text{H}_9\text{F}_2^+$	119.0659	119.0685	0.0026

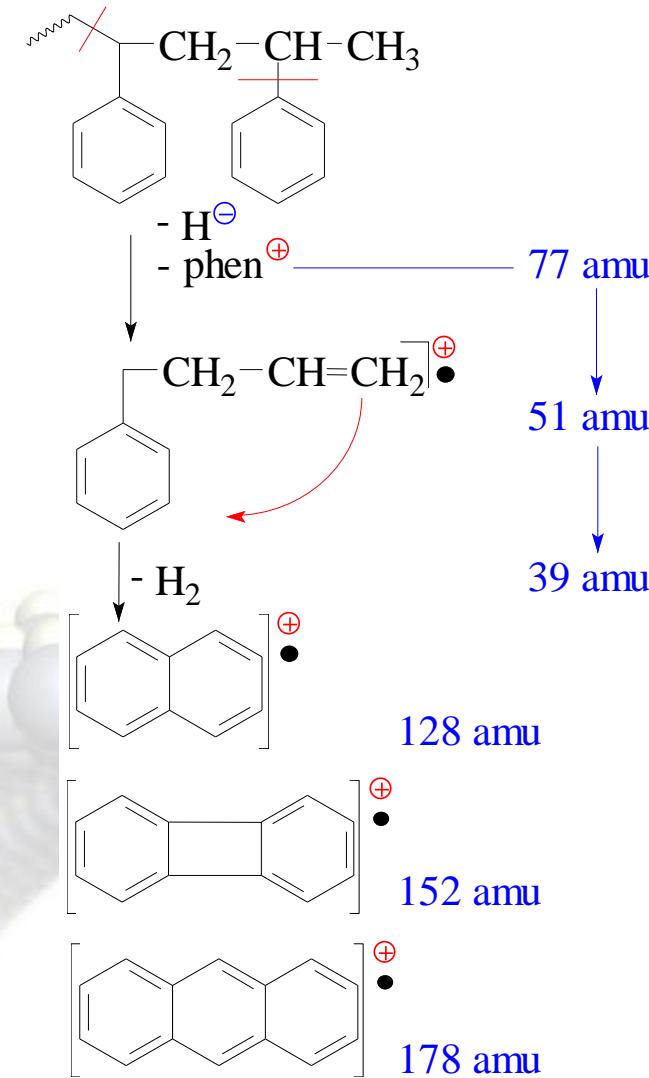
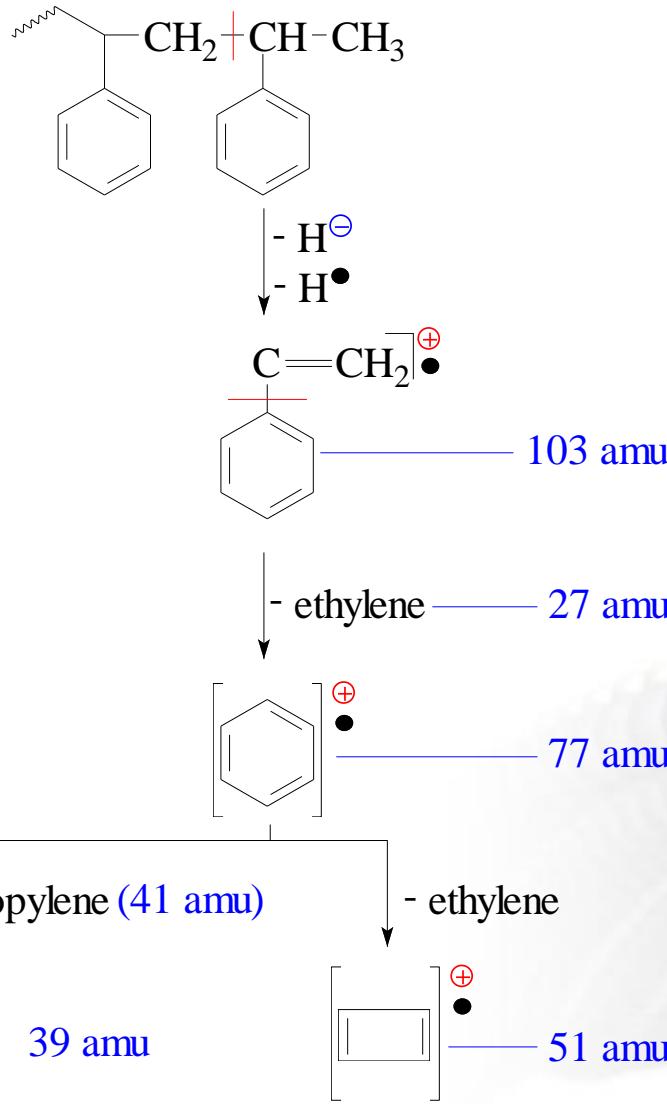
All values were given in [amu]

plasma-treated PTFE



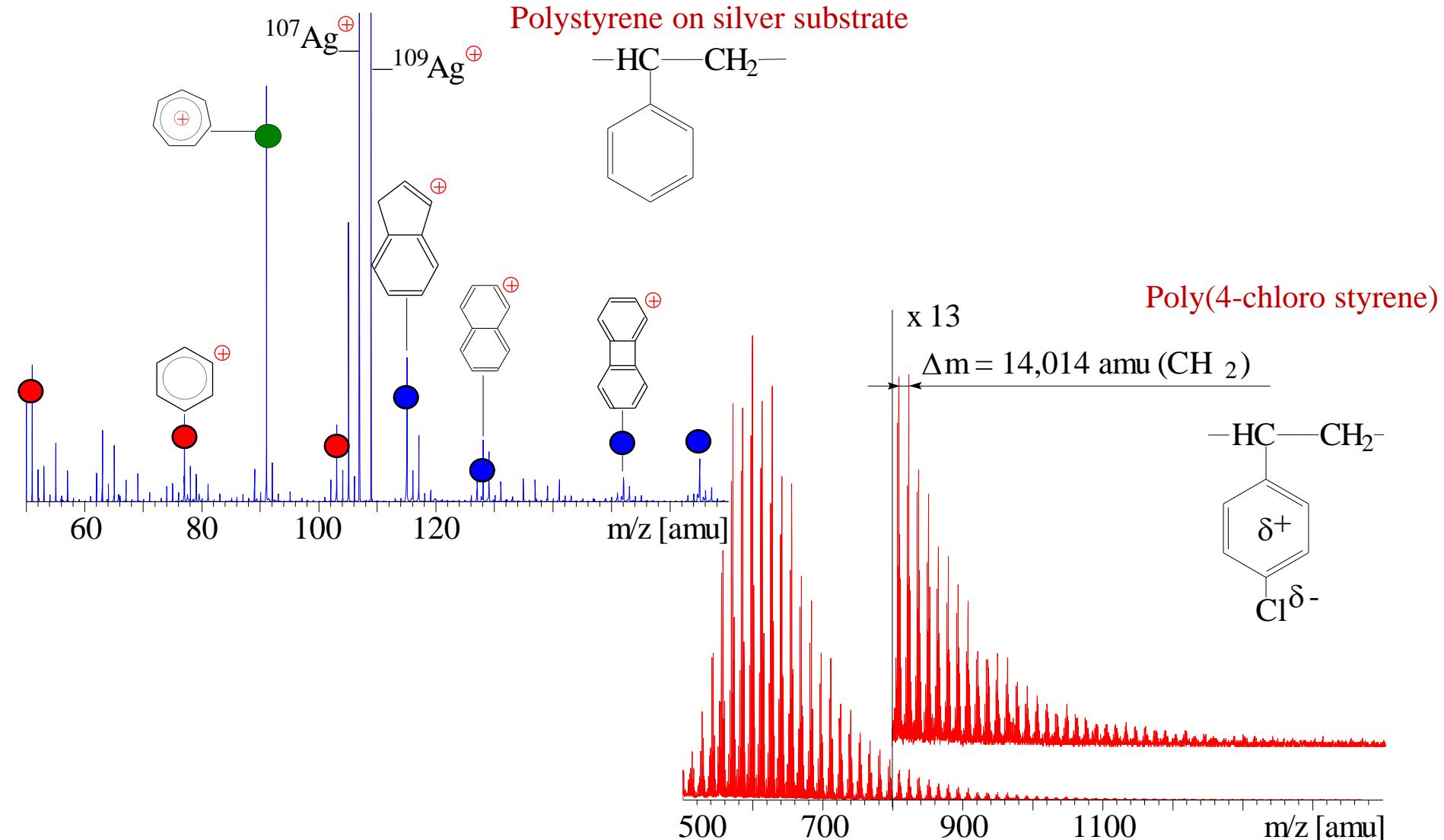
Fragmentation mechanisms

– e.g. Polymers with aromatic units –



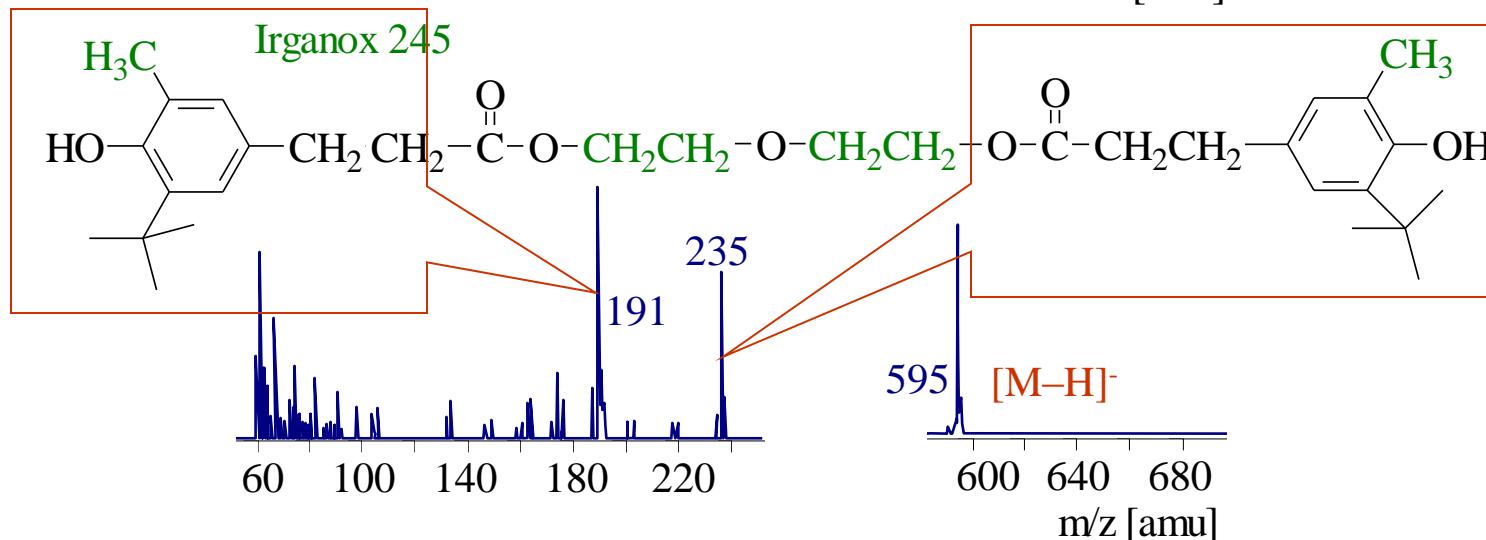
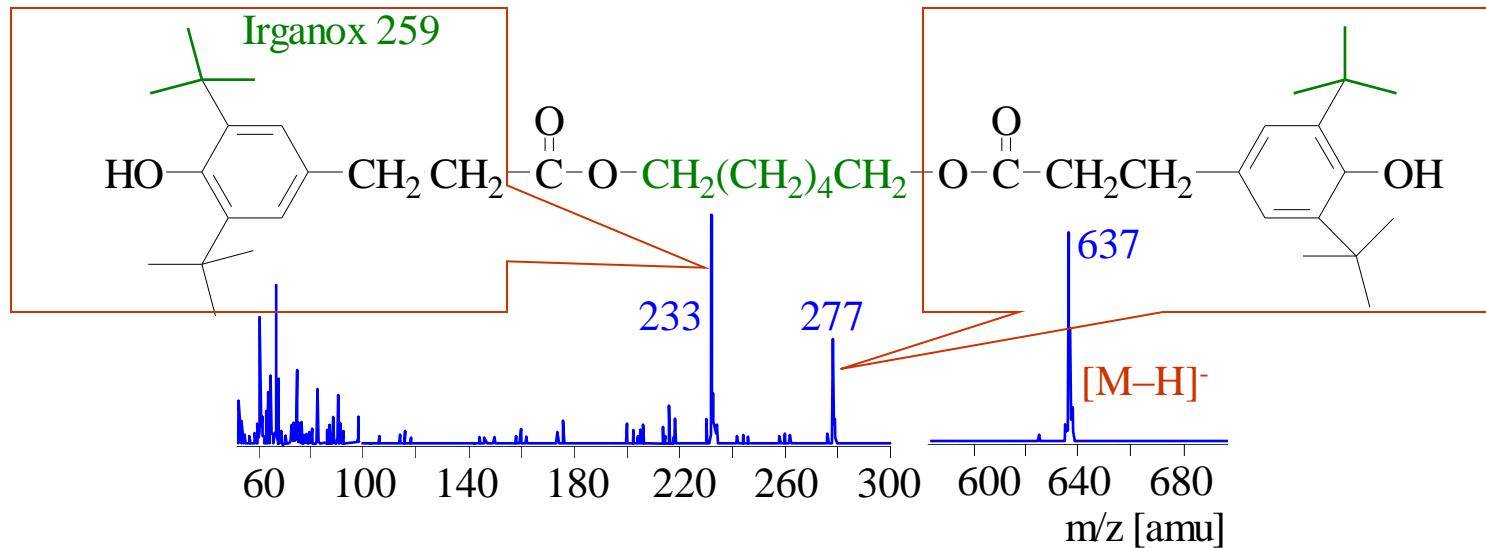
Fragmentation mechanisms

– e.g. Polymers with aromatic units –



Analysis of additives in polymers

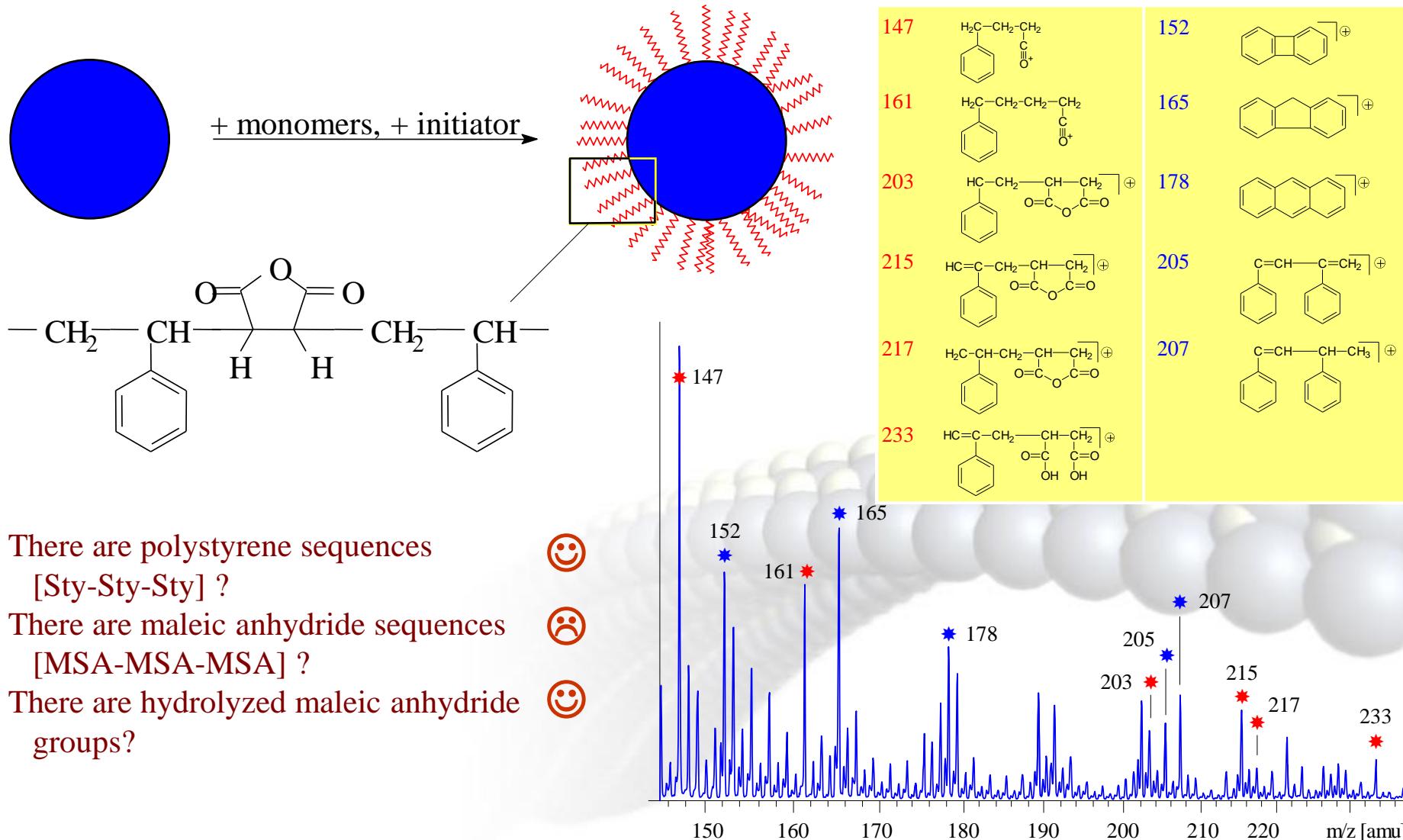
– No chance for XPS –



Analysis of additives, impurities, modifiers etc.

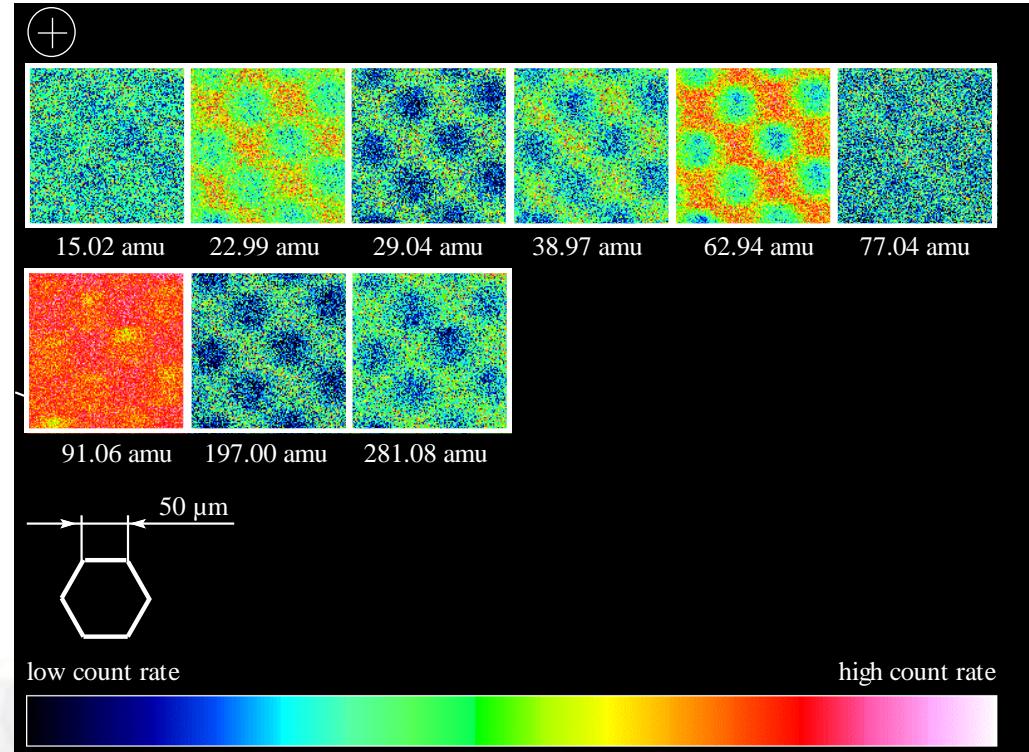
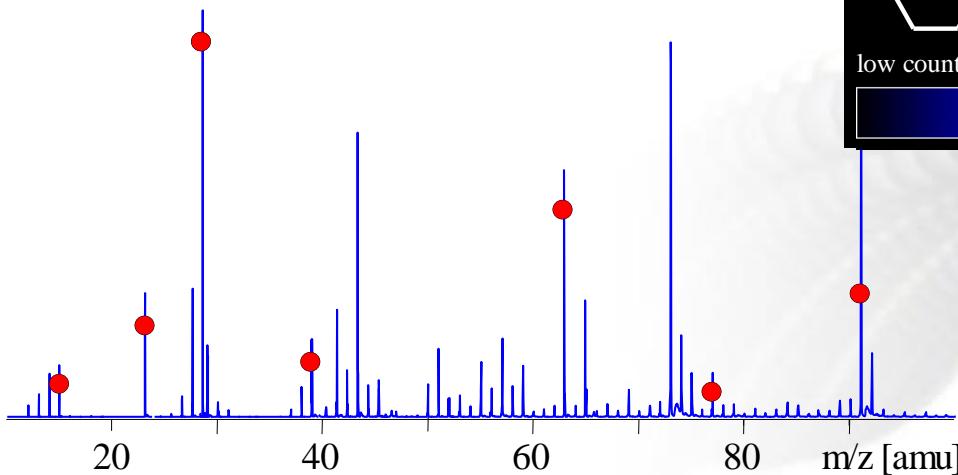
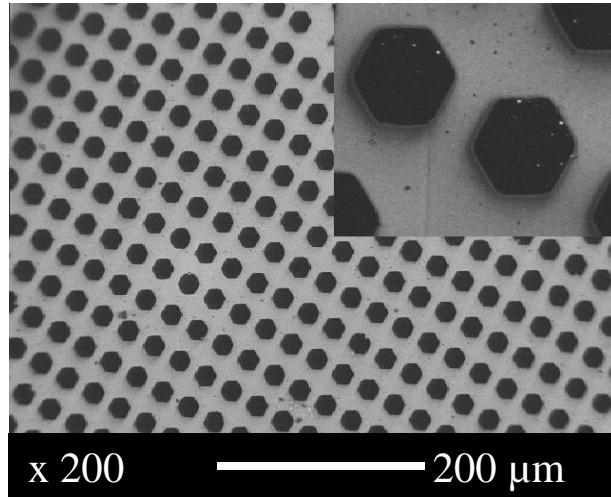
Application note of ToF-SIMS

– Grafting of styrene and maleic anhydride on polyolefin surfaces –



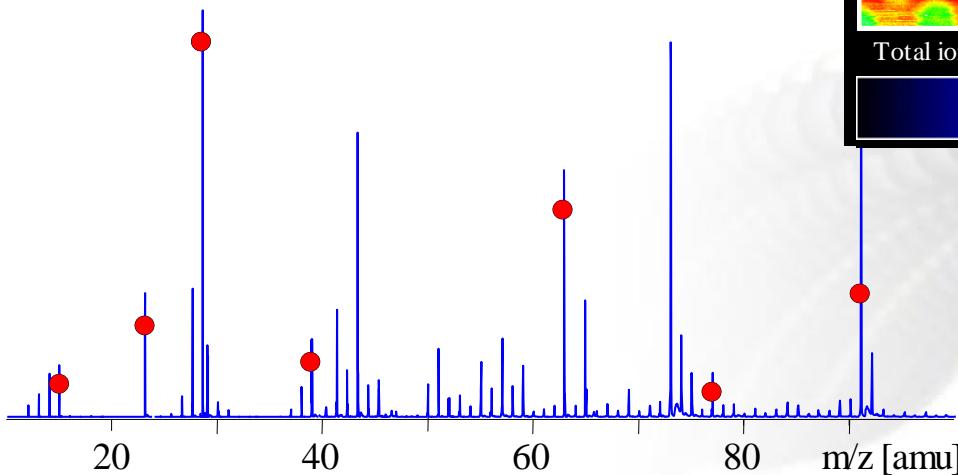
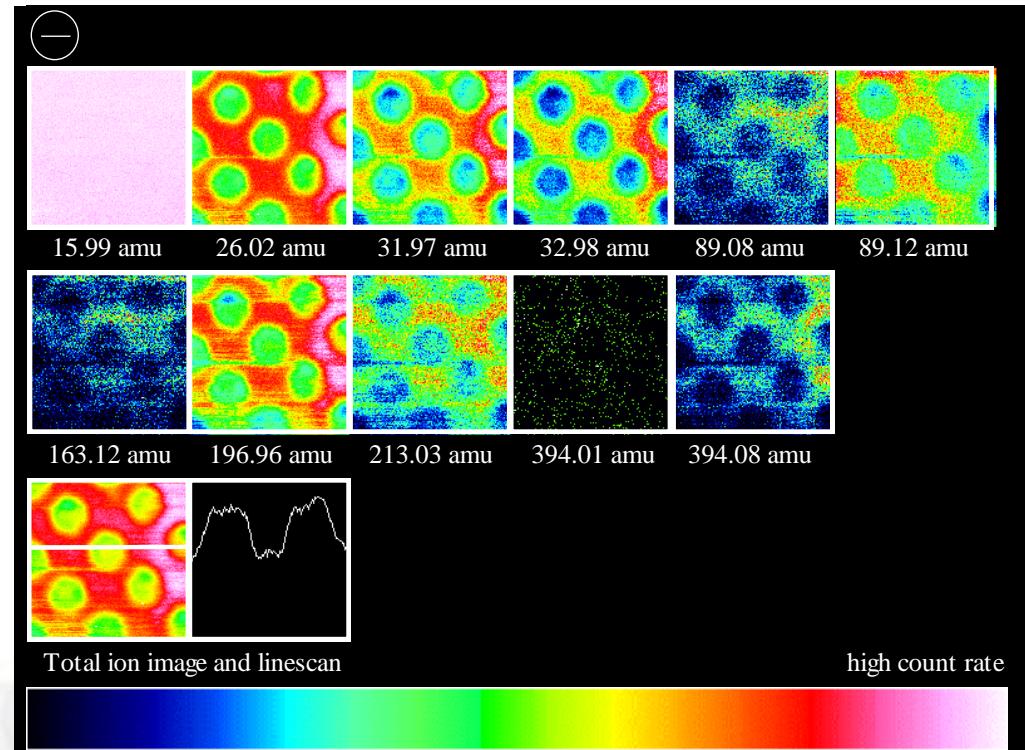
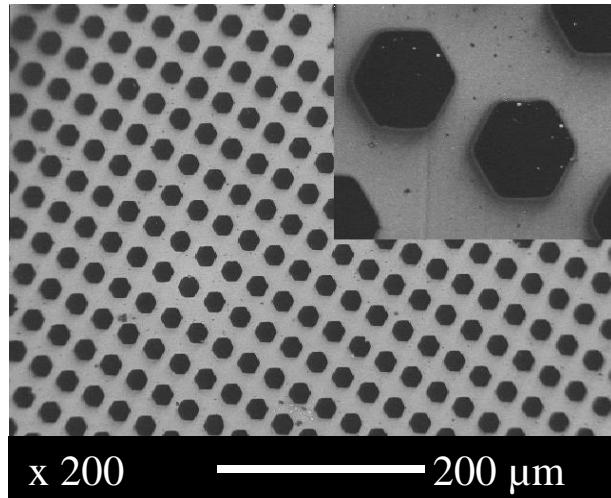
Imaging-ToF-SIMS

– Laterally structured poly(γ -benzyl glutamate) –



Imaging-ToF-SIMS

– Laterally structured poly(γ -benzyl glutamate) –



Summary

SSIMS [ToF-SIMS]

SSIMS is a method oriented to detect and analyse molecules on the surface of samples

- analysis of molecule species [chemical structure and mass of the polymer's repeating units
⇒ type of monomer]
- non-quantitative surface analysis [semi-quantitative surface analysis],
- analysis of end groups Endgruppen ⇒ **determination of molar masses and molar mass distributions** on surfaces
- analysis of additives, impurities, modifiers etc. [**traces can be detected**],
- analysis of structural changes caused by surface modification, functionalization, and aging.